

**Figure 2:** Control block diagram of Mono switch resonant inverter

Fig.2 Shows the Control block diagram of Mono switches resonant converter. The system is controlled entirely by a single 8-bit MCU on the control board with the following features [8]:

- Provides Touch Sense Input (TSI)
- Communicates with the display driver
- Drives the cooling fan and buzzer
- Outputs PWM to the IGBT driver
- Provides feedback from the power stage control
- Detects and measures: noise, temperature, voltage, and current

### 3.1 Temperature sensing and V or I measurement

in Fig. 3. These measured values are input to the MCU internal Analog to Digital Converter.

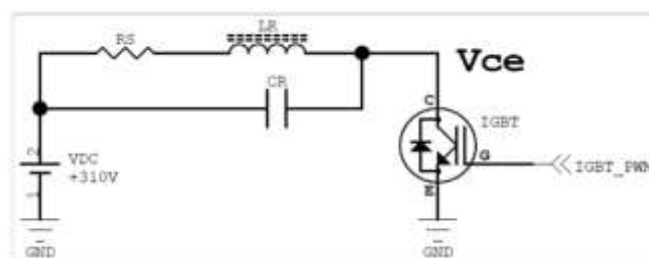
RC filters are kept on the ADC inputs and placed close to the MCU which improve the EMC.

### 3.2 IGBT driver with pulse detection

**Figure 4:** IGBT driver and Pulse detection

The IGBT PWM signal is output from FTM1CH1[8], shown in Fig.4. Logical AND gate with Noise detection for noise protection used. The circuit converts the PWM signal from 5V to 18V so that the IGBT has driven appropriately.

### 3.3 LC Parallel resonator



**Figure 5:** LC Parallel resonant equivalent circuit

A parallel LC Resonant circuit is shown in Fig. 5. As shown, the induction coil and the cookware form the equivalent  $L_r$ , and equivalent resistance  $R_s$ . This circuit resonated with resonant capacitor  $C_r$ . Proper  $C_r$  should be selected so that the LC resonant frequency ( $f_r = 1 / (2\pi \sqrt{L_r C_r})$ ) is higher than 20 KHz to avoid audible frequency [8].

## 4. Specifications and circuit Parameters

**Table 1:** Specifications

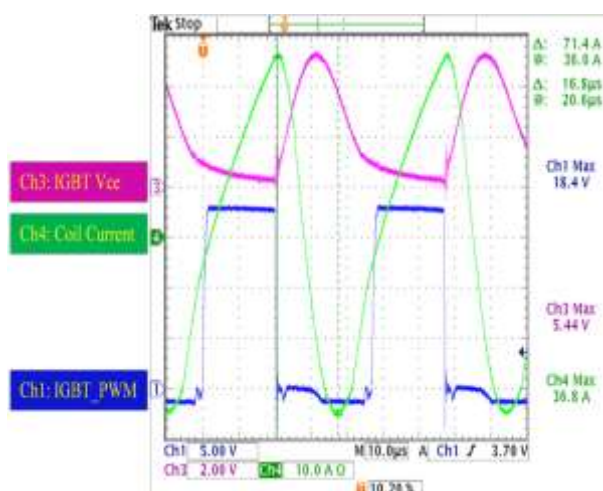
Component	Symbol	Rating
AC input	$V_s, f$	230V, 50Hz
Rectified Voltage	$V_{dc}$	310V
Load inductance	$L_r$	140μH
Resonant Capacitor	$C_r$	0.3μF
Resonant Frequency	$F_r$	24.56kHz

**Figure 3:** Temperature sensing and voltage/current measurement as input to MCU.

For safety and protection, IGBT Temperature sensing, IGBT voltage, and IGBT current measurements are made as shown

Operating switching frequency range	$F_s$	25kHz to 50kHz
IGBT	20N120R3	1200V, 20A
MCU	S08PT	8-bit

## 5. IGBT and Coil current Result waveforms



**Figure 6:** Switch IGBT Voltage, PWM pulse and Coil current

Fig.6 shows voltage across the mono switch  $V_{ce}$ , switching gate pulse for load switching and the load current as coil current. The output power of the mono switch converter controlled by the pulse width of the switching gate pulse. The required PWM pulses obtained from the MCU depending upon the load requirement. The programme is loaded into the MCU for the switching pulse generation according to load requirement. The programming code not presented in this paper. When heating is in progress, the voltage of IGBT ( $V_{ce}$ ) will become higher and exceed the limit if the IGBT over drove or the load removed suddenly. Protection against this kind of situation also achieved by ADC ISR of the MCU. It stops the output of switching pulses to the IGBT driver circuit. The IGBT temperature and the load temperature are monitored continually for safety control.

## 6. Experimental setup



**Figure 7:** Experimental setup of Mono switch converter Circuit with the loaded vessel



**Figure 8:** Experimental setup of Mono switch converter

### Circuit Output Voltage and Current waveforms

Fig.7 shows the experimental setup of the proposed configuration. Fig.8 shows the inverter output voltage, and load current with ZVS. These experimental results are good agreement with simulation results.

## 7. Conclusion

In this paper, mono switch resonant High frequency inverter for induction heating has implemented. The proposed inverter configuration simulated in the multi-sim environment. Experimentally the inverter output power controlled using by programmable PWM of MCU for broad range control. The switching device is operated with ZVS. As the power handled by the inverter is small, and overall efficiency is not affected significantly. The simulation results are validated with the experimental results. The proposed configuration can be extended to multiple loads.

## References

- [1] W.C. Moreland, "The induction range: Its performance and its development problems", IEEE Trans. Ind. Appl., vol. IA-9, no. 1, Jan/Feb. 1973, pp.81-85.
- [2] Mokhtar Kamli, Shigehiro amamoto, Minoru Abe, " A 50 – 150kHz Half-Bridge Inverter for Induction Heating Applications", IEEE Trans. Industrial Electronics, vol. 43, no.1, February 1996,
- [3] S.M.W. Ahmed, M. M. Eissa, M. Edress, T. S. Abdel-Hameed, "Experimental investigation of full bridge Series Resonant Inverters for Induction-Heating cooking appliances", 4<sup>th</sup> IEEE Conference on Industrial Electronics and Applications, ICIEA 2009, Page(s): 3327 – 3332.
- [4] Atsushi Okuno, Hitoshi Kawano, Junming Sun, Manabu Kurokawa, Akira Kojina, Mutsuo Nakaoka, "Feasible Development of Soft – Switched SIT Inverter with Load – Adaptive Frequency-Tracking Control Scheme for Induction Heating", IEEE Trans. Industry Application, vol. 34, no. 4, 1998, pp.713-718.
- [5] Young – Sup Kwon, Sang – Bong Yoo, Dong – Seok Hyun, "Half-Bridge series resonant Inverter for Induction Heating Applications with Load-Adaptive PFM Control Strategy", 14th Applied Power

Electronics Conference and Exposition, APEC'99.vol. 1, 1999, pp.575 – 581.

- [6] F. Forest, E. Laboure, F. Costa, J.Y. Gaspard, "Principle of a multi – load / single converter system for low power Induction Heating", IEEE Trans. Power Electronics, vol. 15, no. 2, 2000, pp.223 – 230.
- [7] Jose M. Burdio, Fernando Monterde, Jose R. Garcia, Luis A. Barragan, Abelardo Martinez, "A Two – Output Series – Resonant Inverter for Induction – Heating Cooking Appliances", IEEE Trans. Power Electronics, vol. 20, Issue:4, 2005, pp.815 – 822.
- [8] [www.freescale.com](http://www.freescale.com)

## Author Profile



**Mahesh G** received the B.Tech. degree in Electrical & Electronics Engineering from Jawaharlal Nehru Technological University Hyderabad in 2005 and M.Tech. degree in Power Electronics & Industrial Drive from Jawaharlal Nehru Technological University Hyderabad in 2011. Since 2007, He has been working as Assistant Professor with the Electrical & Electronics Engineering department, Vasavi College of Engineering, Hyderabad. His interests include power electronics, simulation, resonant inverters and solar charge controllers.



**Sharath Kumar P** received the B.Tech degree in Electrical & Electronics Engineering from Jawaharlal Nehru Technological University Hyderabad in 2006, M.Tech degree in Power System from N.I.T Kurukshetra, Haryana in 2008 and Ph.D degree in Electrical Engineering from N.I.T Warangal, Telangana in 2016. Since 2007, He is currently working as Associate Professor with the Electrical & Electronics Engineering department, CVR College of Engineering, Hyderabad. His research interests high frequency resonant inverters, induction heating applications, and distributed generation.



**Ravi Kumar K** received the B.Tech. degree in Electrical & Electronics Engineering from Jawaharlal Nehru Technological University Hyderabad in 1998 and M.Tech. degree in Power Electronics from Jawaharlal Nehru Technological University Hyderabad in 2005. He obtained his PhD degree in Electrical Engineering from NIT Warangal under the guidance of Prof. M. Sydulu in 2016. Since 2001, He has been working as Associate Professor with the Electrical & Electronics Engineering department, Vasavi College of Engineering, Hyderabad. His interests include power system optimization, AI applications to power systems, Economic operation of power systems, power quality, power system stability, contingency analysis, smart grid, renewable energy systems and power electronics.